SCES045C - JULY 1995 - REVISED FEBRUARY 1999

- Member of the Texas Instruments
 Widebus™ Family
- EPIC ™ (Enhanced-Performance Implanted CMOS) Submicron Process
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

description

This 16-bit buffer/driver is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74ALVCH16240 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. It provides inverting outputs and symmetrical active-low output-enable (OE) inputs.

DGG OR DL PACKAGE (TOP VIEW)

		1	
10E [1	48	20E
1Y1 [2	47] 1A1
1Y2	3	46	1A2
GND [4	45] GND
1Y3 [5	44] 1A3
1Y4 [6] 1A4
V _{CC} [7	42] v _{cc}
2Y1	l ~		2A1
2Y2	9	40	2A2
GND [10] GND
2Y3	11	38	2A3
2Y4 [12	37	2A4
3Y1 [13	36	3A1
3Y2	14	35	3A2
GND [15	34	GND
3Y3	16	33	3A3
3Y4 [17		3A4
V _{CC}	18	31] v _{cc}
4Y1	19	30	4A1
4Y2 L	20	29	4A2
GND [21		GND
4Y3 [4A3
4Y4			4A4
40E [24	25	30E
	_	-	

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74ALVCH16240 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each 4-bit buffer)

INPU	JTS	OUTPUT
OE	Α	Υ
L	Н	L
L	L	Н
Н	Χ	Z

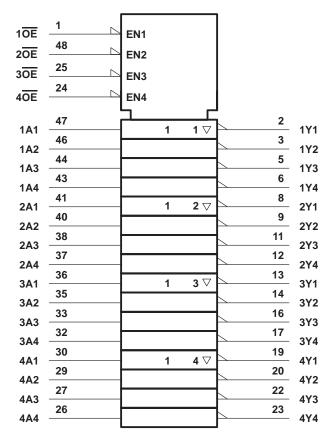
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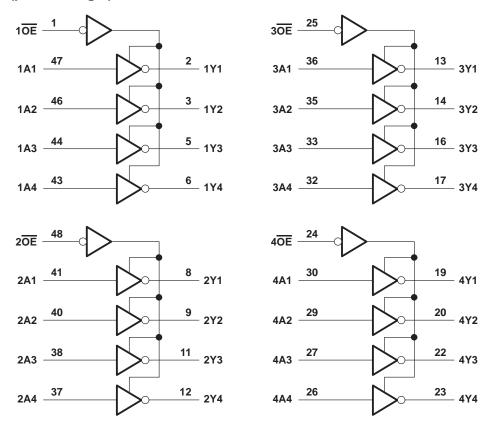
logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Input voltage range, V_I (see Note 1)	
	±100 mA DGG package 89°C/W DL package 94°C/W
Storage temperature range, T _{stg}	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} This value is limited to 4.6 V maximum.

^{3.} The package thermal impedance is calculated in accordance with JESD 51.

SN74ALVCH16240 16-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS SCES045C – JULY 1995 – REVISED FEBRUARY 1999

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
Vcc	Supply voltage			3.6	V	
		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}			
VIH	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		V _{CC} = 1.65 V to 1.95 V		0.35 × V _{CC}		
VIL	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		
٧ı	Input voltage		0	VCC	V	
Vo	Output voltage		0	VCC	V	
		V _{CC} = 1.65 V		-4		
l	High-level output current	V _{CC} = 2.3 V		-12	mA	
ЮН		V _{CC} = 2.7 V		-12		
		V _{CC} = 3 V		-24		
		V _{CC} = 1.65 V		4		
	Low-level output current	V _{CC} = 2.3 V		12		
IOL		V _{CC} = 2.7 V		12	mA	
		VCC = 3 V		24		
Δt/Δν	Input transition rise or fall rate			10	ns/V	
TA	Operating free-air temperature		-40	85	°C	

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST CO	ONDITIONS	Vcc	MIN	TYP [†]	MAX	UNIT		
		I _{OH} = -100 μA		1.65 V to 3.6 V	V _{CC} -0.	2				
Voн		I _{OH} = -4 mA		1.65 V	1.2					
		I _{OH} = -6 mA	2.3 V	2						
				2.3 V	1.7			V		
		I _{OH} = -12 mA		2.7 V	2.2					
				3 V	2.4					
		I _{OH} = -24 mA		3 V	2					
		I _{OL} = 100 μA		1.65 V to 3.6 V			0.2			
		I _{OL} = 4 mA		1.65 V			0.45			
\ _{\/-} .		I _{OL} = 6 mA		2.3 V			0.4			
VOL			2.3 V			0.7	V			
		I _{OL} = 12 mA	2.7 V			0.4				
		I _{OL} = 24 mA	3 V			0.55				
Ц		$V_I = V_{CC}$ or GND		3.6 V			±5	μΑ		
		V _I = 0.58 V		1.65 V	25					
		V _I = 1.07 V	1.65 V	-25			μΑ			
		V _I = 0.7 V	2.3 V	45						
I _I (hold)		V _I = 1.7 V	2.3 V	-45						
`		V _I = 0.8 V		3 V	75					
		V _I = 2 V		3 V	-75			1		
		$V_{I} = 0 \text{ to } 3.6 \text{ V}^{\ddagger}$		3.6 V			±500			
loz		VO = VCC or GND		3.6 V			±10	μΑ		
Icc		$V_I = V_{CC}$ or GND,	IO = 0	3.6 V			40	μΑ		
Δlcc		One input at V _{CC} – 0.6 V,	Other inputs at V _{CC} or GND	3 V to 3.6 V			750	μА		
Ci	Control inputs Data inputs	VI = VCC or GND		3.3 V		3		pF		
Со	Outputs	V _O = V _{CC} or GND		3.3 V		7		pF		

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V	V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
	(INFOT)		TYP	MIN	MAX	MIN	MAX	MIN	MAX	
^t pd	А	Y	§	1	5.3		5.3	1	3.9	ns
t _{en}	ŌĒ	Y	§	1	6.4		6.1	1	5	ns
^t dis	ŌĒ	Y	§	1	5.4		4.8	1	4.4	ns

[§] This information was not available at the time of publication.



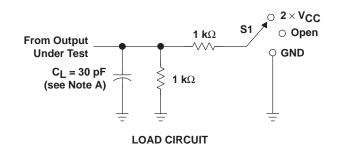
[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C. ‡ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

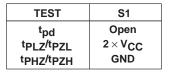
operating characteristics, T_A = 25°C

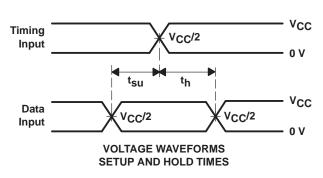
PARAMETER		TEST CONDITIONS	V _{CC} = 1.8 V	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V	UNIT	
<u> </u>	Power dissipation	Outputs enabled	Cı = 50 pF. f = 10 MHz	†	16	19	ρF
C _{pd}	capacitance	Outputs disabled	$C_L = 50 \text{ pF}, f = 10 \text{ MHz}$	†	4	5	PΓ

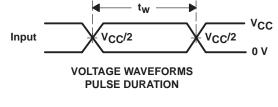
[†] This information was not available at the time of publication.

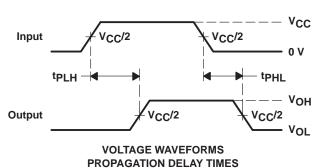
PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V}$

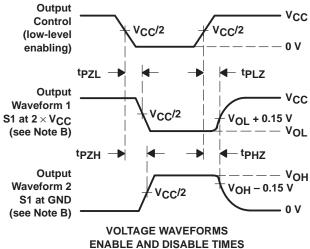










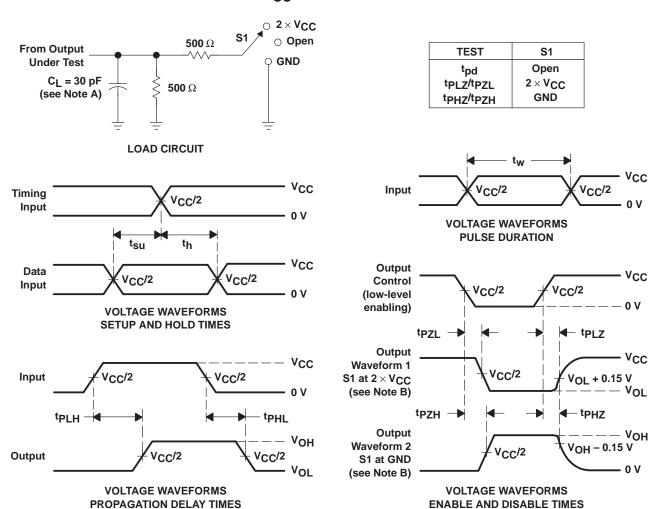


NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2 ns, t_f \leq 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



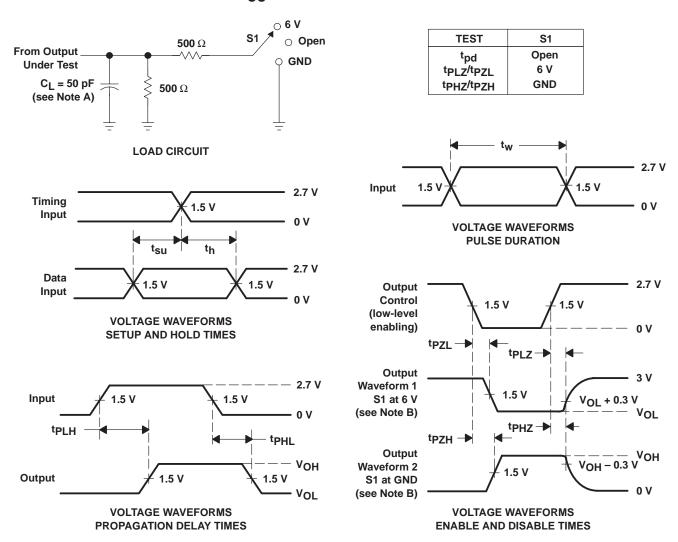
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_Q = 50 Ω , $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.
- F. tpZL and tpZH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.7 \text{ V}$ AND 3.3 V \pm 0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_{O} = 50 \Omega$, $t_{f} \leq$ 2.5 ns. $t_{f} \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.

Figure 3. Load Circuit and Voltage Waveforms



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